/ Descriptions

PDFN5×6 N

N-Channel MOSFET in a PDFN5×6 Plastic Package.

/ Features

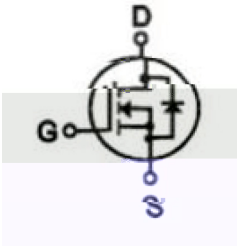
Low $R_{DS(ON)}$ to minimize conductive loss;low Gate Charge for fast switching;Low Thermal resistance;HF Product.

/ Applications

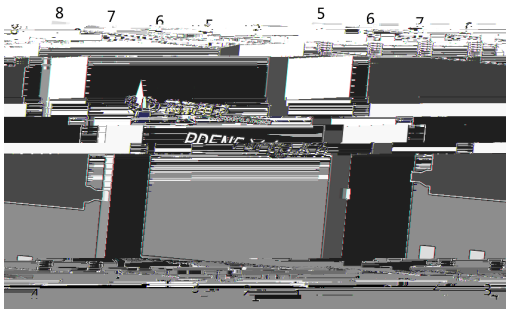
MB/NB/UMPC/VGA Buck -

Battery Management,High Frequency Point-of-Load Synchronous Buck Conventer for MB/NB/UMPC/VGA,Networking DC-DC Power System,Load Switch.

/ Equivalent Circuit



/ Pinning



PIN1 2 3 S PIN4 G PIN5 6 7 8 D

Pin	极性
1	S
2	S
3	S
4	G
5	D
6	D

/ Marking

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	40	V
Drain Current - Continuous	I_D	100	A
Drain Current – Pulsed	I_{DM}	285	A
Gate-Source Voltage	V_{GS}	± 20	V
Power Dissipation	$P_D(T_c=25$)	78	W
Single Pulse Avalanche Energy(L=0.5mH)	E_{AS}	220	mJ
Avalanche Curre			

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	V_{GS}=10V V_{DS}=20V R_L=1.0Ω R_{GEN}=3Ω		11		ns
Turn-On Rise Time	t_r			3.5		
Turn-Off Delay Time	$t_{d(off)}$			36		
Turn-Off Fall Time	t_f			3		

/ Electrical Characteristic Curve

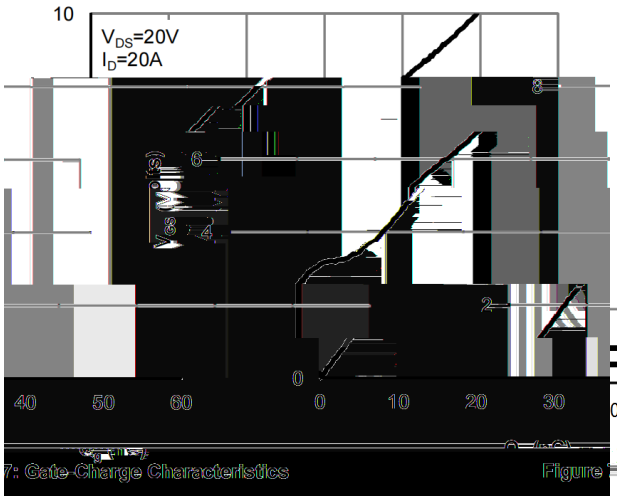
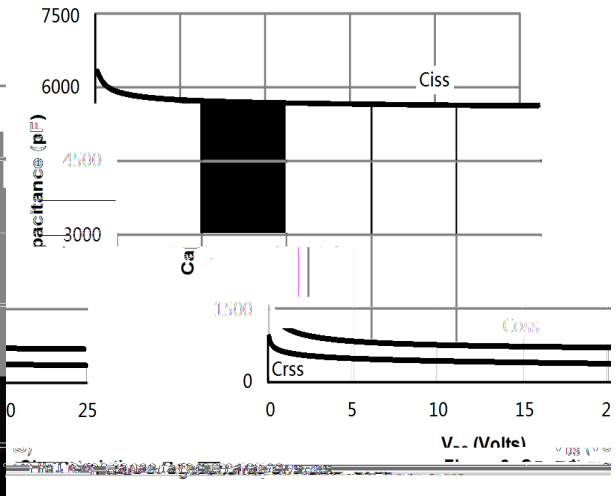


Figure 7: Gate Charge Characteristics



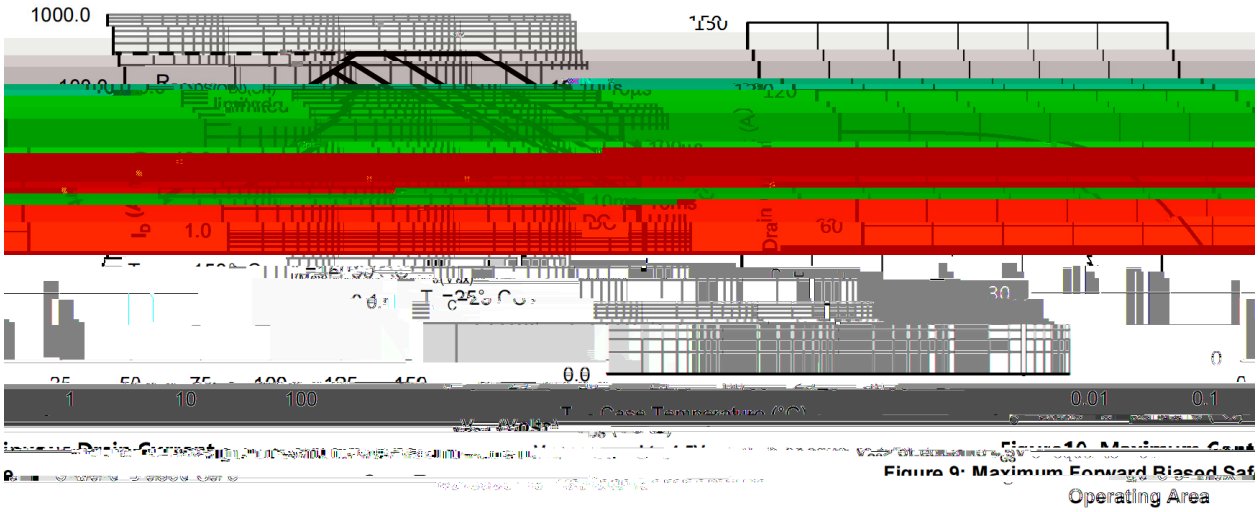
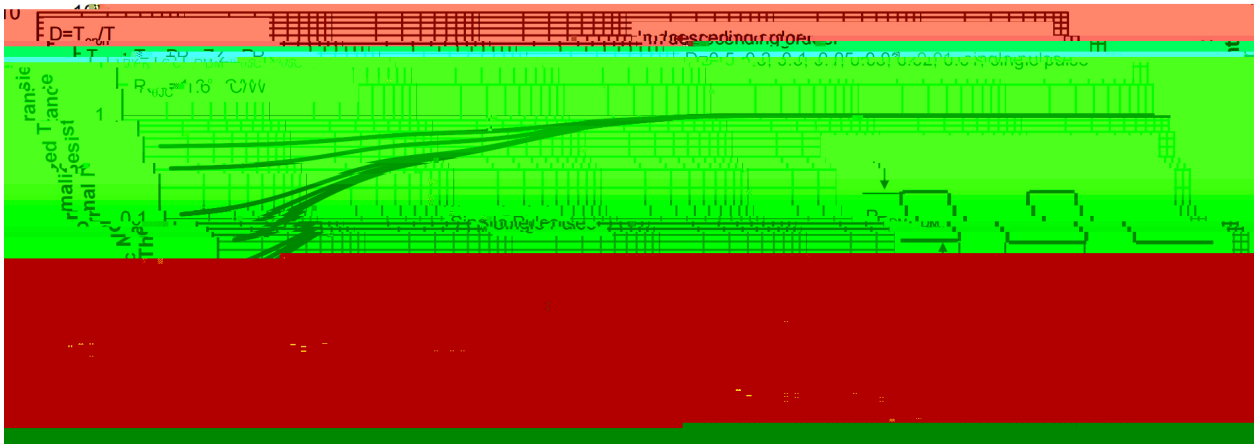
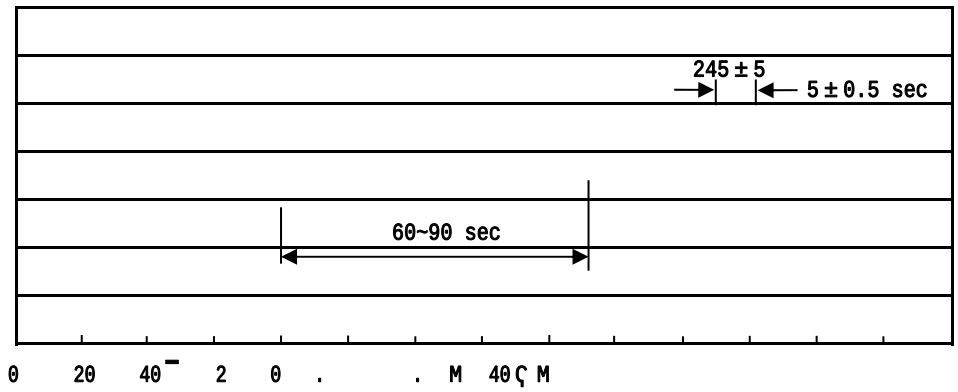


Figure 9: Maximum Forward Biased Safe Operating Area



BRCS020N04ZC

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



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